NSN 5962-01-273-8049

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View Online at https://aerobasegroup.com/nsn/5962-01-273-8049

Body Length:	
0.840 inches	
Body Width:	
0.310 inches	
Body Height:	
0.185 inches	
Aximum Power Dissipation Rating:	
739.0 milliwatts	
Operating Tempurature Range:	
55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
65.0/+150.0 degrees celsius	
Features Provided:	
ermetically sealed and burn in and bipolar and schottky and programmable and w/active pull-up	
nclosure Material:	
Ceramic	
nclosure Configuration:	
Dual-in-line	
Dutput Logic Form:	
ransistor-transistor logic	
nput Circuit Pattern:	
0 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Ferminal Surface Treatment:	
Solder	
/oltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to	o low level
putput	
lemory Device Type:	
Rom	
Nemory Capacity:	
Jnknown	
Test Data Document:	
06906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Ferminal Type And Quantity:	
6 printed circuit	
Shelf Life:	
l/a	
Jnit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

